

November 2007

## KSD1616/1616A

### **Audio Frequency Power Amplifier & Medium Speed Switching**

· Complement to KSB1116/1116A



## **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter		Ratings	Units	
V <sub>CBO</sub>	Collector-Base Voltage	: KSD1616 : KSD1616A	60 120	V V	
V <sub>CEO</sub>	Collector-Emitter Voltage	: KSD1616 : KSD1616A	50 60	V V	
$V_{EBO}$	Emitter-Base Voltage		6	V	
I <sub>C</sub>	Collector Current (DC)		1	Α	
I <sub>CP</sub>	* Collector Current (Pulse)		2	Α	
P <sub>C</sub>	Collector Power Dissipation		0.75	W	
TJ	Junction Temperature		150	°C	
T <sub>STG</sub>	Storage Temperature		-55 ~ 150	°C	

<sup>\*</sup> PW $\leq$ 10ms, Duty Cycle < 50%

# $\textbf{Electrical Characteristics} \ \, \textbf{T}_{a} \text{=} 25 ^{\circ} \textbf{C} \ \, \text{unless otherwise noted}$

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =60V, I <sub>E</sub> =0			100	nA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB}$ =6V, $I_C$ =0			100	nA
h <sub>FE1</sub>	DC Current Gain : KSD1616 : KSD1616A	V <sub>CE</sub> =2V, I <sub>C</sub> =100mA	135 135		600 400	
h <sub>FE2</sub>		V <sub>CE</sub> =2V, I <sub>C</sub> =1A	81			
V <sub>BE</sub> (on)	* Base-Emitter On Voltage	V <sub>CE</sub> =2V, I <sub>C</sub> =50mA	600	640	700	mV
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	I <sub>C</sub> =1A, I <sub>B</sub> =50mA		0.15	0.3	V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	I <sub>C</sub> =1A, I <sub>B</sub> =50mA		0.9	1.2	V
C <sub>ob</sub>	Output Capacitance	V <sub>CE</sub> =10V, I <sub>E</sub> =0, f=1MHz		19		pF
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =2V, I <sub>C</sub> =100mA	100	160		MHz
t <sub>ON</sub>	Turn On Time	V <sub>CC</sub> =10V, I <sub>C</sub> =100mA		0.07		μS
t <sub>STG</sub>	Storage Time	I <sub>B1</sub> = -I <sub>B2</sub> =10mA		0.95		μS
t <sub>F</sub>	Fall Time	$V_{BE}$ (off) = -2~-3V		0.07		μS

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<sup>\*</sup> Pulse Test: PW<350μs, Duty Cycle≤2% Pulsed

# h<sub>FE1</sub> Classification

Classification	Y	G	L
h <sub>FE1</sub>	135 ~ 270	200 ~ 400	300 ~ 600

## **Typical Characteristics**

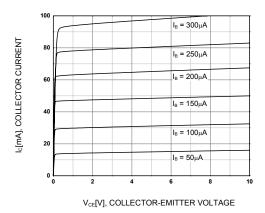


Figure 1. Static Characteristic

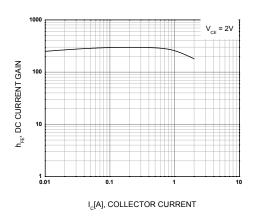


Figure 3. DC current Gain

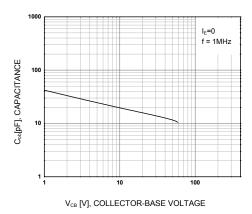


Figure 5. Collector Output Capacitance

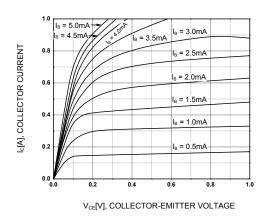


Figure 2. Static Characteristic

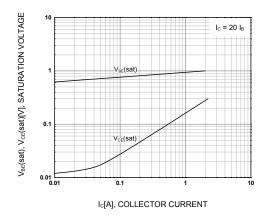


Figure 4. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

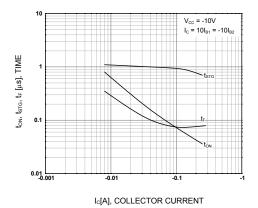


Figure 6. Switching Time

## Typical Characteristics(Continued)

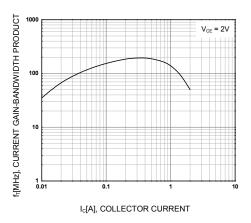


Figure 7. Current Gain Bandwidth Product

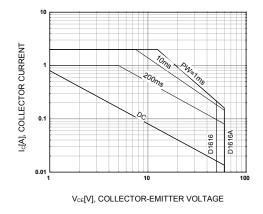


Figure 8. Safe Operating Area

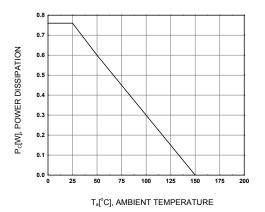


Figure 9. Power Derating





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